

Miniature Single-Cell, Fully Integrated Li-Ion, Li-Polymer Charge Management Controllers

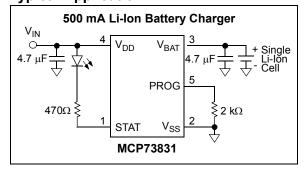
Features:

- · Linear Charge Management Controller:
 - Integrated Pass Transistor
 - Integrated Current Sense
 - Reverse Discharge Protection
- High Accuracy Preset Voltage Regulation: ± 0.75%
- · Four Voltage Regulation Options:
 - 4.20V, 4.35V, 4.40V, 4.50V
- · Programmable Charge Current: 15 mA to 500 mA
- · Selectable Preconditioning:
 - 10%, 20%, 40%, or Disable
- · Selectable End-of-Charge Control:
 - 5%, 7.5%, 10%, or 20%
- · Charge Status Output
 - Tri-State Output MCP73831
 - Open-Drain Output MCP73832
- · Automatic Power-Down
- · Thermal Regulation
- Temperature Range: -40°C to +85°C
- · Packaging:
 - 8-Lead, 2 mm x 3 mm DFN
 - 5-Lead, SOT-23

Applications:

- · Lithium-Ion/Lithium-Polymer Battery Chargers
- · Personal Data Assistants
- · Cellular Telephones
- Digital Cameras
- · MP3 Players
- · Bluetooth Headsets
- · USB Chargers

Typical Application



Description:

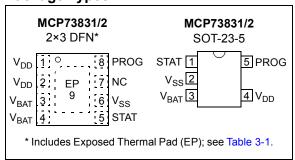
The MCP73831/2 devices are highly advanced linear charge management controllers for use in space-limited, cost-sensitive applications. The MCP73831/2 are available in an 8-Lead, 2 mm x 3 mm DFN package or a 5-Lead, SOT-23 package. Along with their small physical size, the low number of external components required make the MCP73831/2 ideally suited for portable applications. For applications charging from a USB port, the MCP73831/2 adhere to all the specifications governing the USB power bus.

The MCP73831/2 employ a constant-current/constant-voltage charge algorithm with selectable preconditioning and charge termination. The constant voltage regulation is fixed with four available options: 4.20V, 4.35V, 4.40V or 4.50V, to accommodate new, emerging battery charging requirements. The constant current value is set with one external resistor. The MCP73831/2 devices limit the charge current based on die temperature during high power or high ambient conditions. This thermal regulation optimizes the charge cycle time while maintaining device reliability.

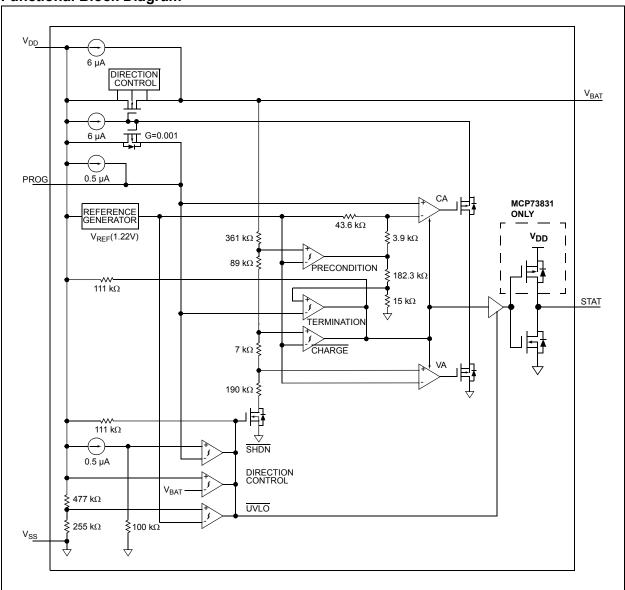
Several options are available for the preconditioning threshold, preconditioning current value, charge termination value and automatic recharge threshold. The preconditioning value and charge termination value are set as a ratio or percentage of the programmed constant current value. Preconditioning can be disabled. Refer to Section 1.0 "Electrical Characteristics" for available options and the Product Identification System for standard options.

The MCP73831/2 devices are fully specified over the ambient temperature range of -40°C to +85°C.

Package Types



Functional Block Diagram



1.0 **ELECTRICAL CHARACTERISTICS**

Absolute Maximum Ratings†

V _{DD} 7.0V
All Inputs and Outputs w.r.t. $\rm V_{SS}$ 0.3 to $\rm (V_{DD} + 0.3) V$
$\label{eq:maximum Junction Temperature, T_JInternally Limited} \label{eq:maximum Junction Temperature, T_JInternally Limited}$
Storage temperature65°C to +150°C
ESD protection on all pins:
Human Body Model (1.5 k Ω in Series with 100 pF) \geq 4 kV
Machine Model (200 pF, No Series Resistance)400V

† Notice: Stresses above those listed under "Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

DC CHARACTERISTICS

Electrical Specifications: Unless otherwise indicated, all limits apply for $V_{DD} = [V_{REG}(typical) + 0.3V]$ to 6V, $T_A = -40^{\circ}C$ to +85°C. Typical values are at +25°C, $V_{DD} = [V_{REG} \text{ (typical)} + 1.0V]$ Sym. **Parameters** Min. Max. Units Conditions Тур. Supply Input Supply Voltage 3.75 ٧ V_{DD} 6 Supply Current 510 1500 μΑ Charging I_{SS} 53 200 Charge Complete, No Battery 25 50 PROG Floating μΑ 5 μΑ 1 $V_{DD} \leq (V_{BAT} - 50 \text{ mV})$ 0.1 2 μΑ $V_{DD} < V_{STOP}$ **UVLO Start Threshold** 3.45 3.6 ٧ V_{DD} Low-to-High 33 V_{START} **UVLO Stop Threshold** V_{STOP} 3.2 3.38 3.5 V V_{DD} High-to-Low **UVLO** Hysteresis 70 V_{HYS} mV Voltage Regulation (Constant-Voltage Mode) Regulated Output Voltage 4.168 4.20 4.232 ٧ MCP7383X-2 V_{REG} 4.317 4.35 4.383 ٧ MCP7383X-3 4.40 4.433 MCP7383X-4 4.367 ٧ 4.50 MCP7383X-5 4.466 4.534 V $V_{DD} = [V_{REG}(typical)+1V]$ $I_{OUT} = 10 \text{ mA}$ $T_A = -5^{\circ}C \text{ to } +55^{\circ}C$ $|(\Delta V_{BAT}/$ Line Regulation 0.09 0.30 %/V $V_{DD} = [V_{REG}(typical)+1V]$ to $V_{BAT})/\Delta V_{DD}$ 6V, I_{OUT} = 10 mA I_{OUT} = 10 mA to 50 mA Load Regulation $|\Delta V_{BAT}/V_{BAT}|$ 0.05 0.30 % $V_{DD} = [V_{REG}(typical)+1V]$ **PSRR** Supply Ripple Attenuation 52 dB I_{OUT}=10 mA, 10Hz to 1 kHz 47 dΒ I_{OUT} =10 mA, 10Hz to 10 kHz I_{OUT} =10 mA, 10Hz to 1 MHz 22 dΒ **Current Regulation (Fast Charge Constant-Current Mode)** 100 PROG = 10 $k\Omega$ Fast Charge Current 90 110 mΑ I_{REG} Regulation

505

14.5

550

16.5

mA

mΑ

450

12.5

Note 1: Not production tested. Ensured by design.

PROG = $2.0 \text{ k}\Omega$, Note 1

PROG = 67 k Ω

 $T_A = -5$ °C to +55°C

DC CHARACTERISTICS (CONTINUED)

Electrical Specifications: Unless otherwise indicated, all limits apply for V_{DD} = [V_{REG} (typical) + 0.3V] to 6V, T_A = -40°C to +85°C. Typical values are at +25°C, V_{DD} = [V_{REG} (typical) + 1.0V]

Parameters	Sym.	Min.	Тур.	Max.	Units	Conditions
Preconditioning Current	Regulation (Tri	ckle Charge Co		Mode)		1
Precondition Current	I _{PREG} / I _{REG}	7.5	10	12.5	%	PROG = 2.0 kΩ to 10 kΩ
Ratio		15	20	25	%	PROG = 2.0 kΩ to 10 kΩ
		30	40	50	%	PROG = 2.0 kΩ to 10 kΩ
		_	100	_	%	No Preconditioning
						$T_A = -5^{\circ}C \text{ to } +55^{\circ}C$
Precondition Voltage	V _{PTH} / V _{REG}	64	66.5	69	%	V _{BAT} Low-to-High
Threshold Ratio		69	71.5	74	%	V _{BAT} Low-to-High
Precondition Hysteresis	V _{PHYS}	_	110	_	mV	V _{BAT} High-to-Low
Charge Termination					•	-
Charge Termination	I _{TERM} / I _{REG}	3.75	5	6.25	%	PROG = 2.0 kΩ to 10 kΩ
Current Ratio		5.6	7.5	9.4	%	PROG = $2.0 \text{ k}\Omega$ to $10 \text{ k}\Omega$
		8.5	10	11.5	%	PROG = $2.0 \text{ k}\Omega$ to $10 \text{ k}\Omega$
		15	20	25	%	PROG = $2.0 \text{ k}\Omega$ to $10 \text{ k}\Omega$
						$T_A = -5^{\circ}C$ to $+55^{\circ}C$
Automatic Recharge					•	
Recharge Voltage	V _{RTH} / V _{REG}	91.5	94.0	96.5	%	V _{BAT} High-to-Low
Threshold Ratio		94	96.5	99	%	V _{BAT} High-to-Low
Pass Transistor ON-Resi	stance					
ON-Resistance	R _{DSON}	_	350	_	mΩ	V_{DD} = 3.75V, T_{J} = 105°C
Battery Detection						
Battery Detection Current	I _{BAT_DET}	_	6	_	μA	V _{BAT} Source Current
No-Battery-Present Threshold	V _{NO_BAT}	_	V _{REG} + 100 mV	_	٧	V _{BAT} Voltage ≥ V _{NO_BAT} for No Battery condition
No-Battery-Present Impedance	Z _{NO_BAT}	2	_	_	ΜΩ	V _{BAT} Impedance ≥ Z _{NO_BAT} for No Battery condition, Note 1
Battery Discharge Curre	nt		<u> </u>		II.	<u> </u>
Output Reverse Leakage	I _{DISCHARGE}	_	0.15	2	μA	PROG Floating
Current	DIOO! WITOE	_	0.25	2	μA	V _{DD} Floating
		_	0.15	2	μA	V _{DD} < V _{STOP}
		_	-5.5	-15	μA	Charge Complete
Status Indicator – STAT	1		1			
Sink Current	I _{SINK}	_	_	25	mA	
Low Output Voltage	V _{OL}	_	0.4	1	V	I _{SINK} = 4 mA
Source Current	I _{SOURCE}	_	_	35	mA	
High Output Voltage	V _{OH}	_	V _{DD} -0.4	V _{DD} - 1	V	I _{SOURCE} = 4 mA (MCP73831)
Input Leakage Current	I _{LK}	_	0.03	1	μA	High-Impedance
PROG Input			. "		•	•
Charge Impedance Range	R _{PROG}	2	_	67	kΩ	
Minimum Shutdown Impedance	R _{PROG}	70	_	200	kΩ	
Automatic Power Down	ı		<u>. </u>		1	
Automatic Power Down Entry Threshold	V _{PDENTER}	V _{DD} <(V _{BAT} +20 mV)	V _{DD} <(V _{BAT} +50 mV)	_		$3.5V \le V_{BAT} \le V_{REG}$ V_{DD} Falling

Note 1: Not production tested. Ensured by design.

DC CHARACTERISTICS (CONTINUED)

Electrical Specifications: Unless otherwise indicated, all limits apply for $V_{DD} = [V_{REG}(typical) + 0.3V]$ to 6V, $T_A = -40$ °C to +85°C. Typical values are at +25°C, $V_{DD} = [V_{REG}(typical) + 1.0V]$

Typical values are at 120 c	, VDD LVREG	(typical) · 1.0 v]				
Parameters	Sym.	Min.	Тур.	Max.	Units	Conditions
Automatic Power Down Exit Threshold	V _{PDEXIT}	_	V _{DD} <(V _{BAT} +150 mV)	V _{DD} <(V _{BAT} +200 mV)		$3.5V \le V_{BAT} \le V_{REG}$ $V_{DD} \text{ Rising}$
Thermal Shutdown						
Die Temperature	T _{SD}	_	150	_	°C	
Die Temperature Hysteresis	T _{SDHYS}	_	10	_	°C	

Note 1: Not production tested. Ensured by design.

AC CHARACTERISTICS

Electrical Specifications: Unless otherwise indicated, all limits apply for $V_{DD} = [V_{REG} \text{ (typical)} + 0.3V] \text{ to } 12V$, $T_A = -40$ °C to +85°C. Typical values are at +25°C, $V_{DD} = [V_{REG} \text{ (typical)} + 1.0V]$ **Parameters** Тур. Max. Units **Conditions** Sym. Min. 5 V_{DD} Low-to-High **UVLO Start Delay** t_{START} ms **Constant-Current Regulation** Transition Time Out of 1 $V_{BAT} < V_{PTH}$ to $V_{BAT} > V_{PTH}$ ms t_{DELAY} Preconditioning Current Rise Time Out of 1 ms I_{OUT} Rising to 90% of I_{REG} t_{RISE} Preconditioning **Termination Comparator** 3.2 t_{TFRM} 0.4 1.3 ms Average I_{OUT} Falling Charge Comparator Filter 0.4 1.3 3.2 ms Average V_{BAT} t_{CHARGE} **Status Indicator** Status Output turn-off 200 I_{SINK} = 1 mA to 0 mA toff μS Status Output turn-on 200 μS I_{SINK} = 0 mA to 1 mA t_{ON}

TEMPERATURE SPECIFICATIONS

Electrical Specifications: Unless otherwise indicated, all limits apply for $V_{DD} = [V_{REG} \text{ (typical)} + 0.3V] \text{ to } 12V.$ Typical values are at +25°C, $V_{DD} = [V_{REG} \text{ (typical)} + 1.0V]$ **Parameters** Sym. Min. Тур. Max. Units Conditions Temperature Ranges Specified Temperature Range -40 +85 °C T_A °C Operating Temperature Range -40 +125 T_{J} °C Storage Temperature Range T_A -65 +150 **Thermal Package Resistances** 5-Lead, SOT-23 θ_{JA} 230 °C/W 4-Layer JC51-7 Standard Board, Natural Convection (Note 2) 4-Layer JC51-7 Standard 8-Lead, 2 mm x 3 mm, DFN °C/W 76 θ_{JA} Board, Natural Convection

Note 1: This represents the minimum copper condition on the PCB (Printed Circuit Board).

^{2:} With large copper area on the PCB, the SOT-23-5 thermal resistance (θ_{JA}) can reach a typical value of 130°C/W or better.

NOTES:

2.0 TYPICAL PERFORMANCE CURVES

Note: The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

Note: Unless otherwise indicated, $V_{DD} = [V_{REG}(typical) + 1V]$, $I_{OUT} = 10$ mA and $T_A = +25$ °C, Constant-Voltage mode.

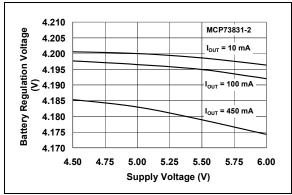


FIGURE 2-1: Battery Regulation Voltage (V_{BAT}) vs. Supply Voltage (V_{DD}) .

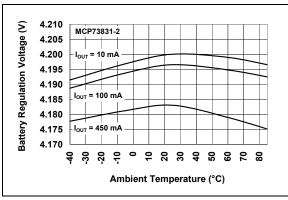


FIGURE 2-2: Battery Regulation Voltage (V_{BAT}) vs. Ambient Temperature (T_A) .

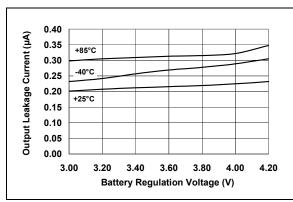


FIGURE 2-3: Output Leakage Current $(I_{DISCHARGE})$ vs. Battery Regulation Voltage (V_{BAT}) .

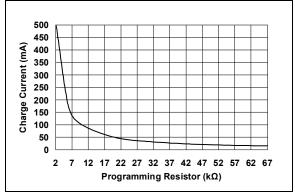


FIGURE 2-4: Charge Current (I_{OUT}) vs. Programming Resistor (R_{PROG}) .

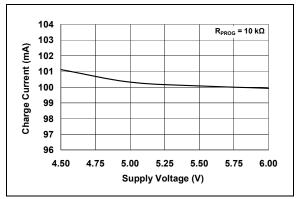


FIGURE 2-5: Charge Current (I_{OUT}) vs. Supply Voltage (V_{DD}).

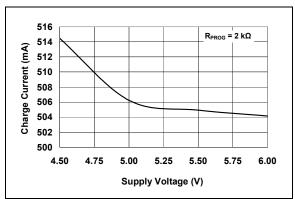


FIGURE 2-6: Charge Current (I_{OUT}) vs. Supply Voltage (V_{DD}) .

TYPICAL PERFORMANCE CURVES (CONTINUED)

Note: Unless otherwise indicated, $V_{DD} = [V_{REG}(typical) + 1V]$, $I_{OUT} = 10$ mA and $T_A = +25$ °C, Constant-Voltage mode.

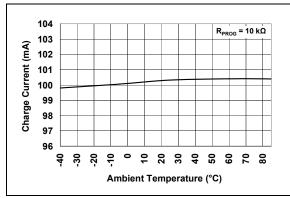


FIGURE 2-7: Charge Current (I_{OUT}) vs. Ambient Temperature (T_A).

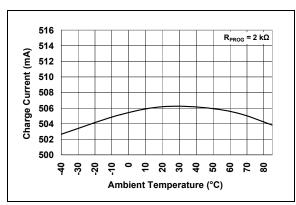


FIGURE 2-8: Charge Current (I_{OUT}) vs. Ambient Temperature (T_A).

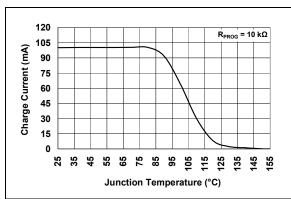


FIGURE 2-9: Charge Current (I_{OUT}) vs. Junction Temperature (T_1) .

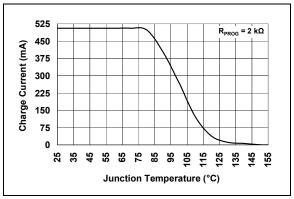


FIGURE 2-10: Charge Current (I_{OUT}) vs. Junction Temperature (T_J).

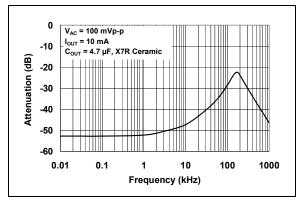


FIGURE 2-11: Power Supply Ripple Rejection (PSRR).

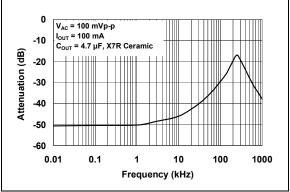


FIGURE 2-12: Power Supply Ripple Rejection (PSRR).

TYPICAL PERFORMANCE CURVES (CONTINUED)

Note: Unless otherwise indicated, $V_{DD} = [V_{REG}(typical) + 1V]$, $I_{OUT} = 10$ mA and $T_A = +25$ °C, Constant-Voltage mode.

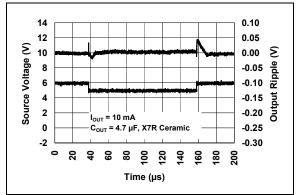


FIGURE 2-13: Line Transient Response.

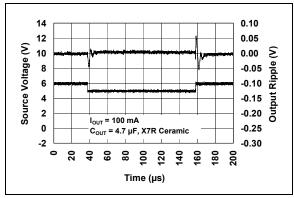


FIGURE 2-14: Line Transient Response.

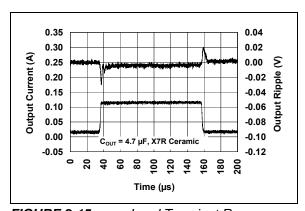


FIGURE 2-15: Load Transient Response.

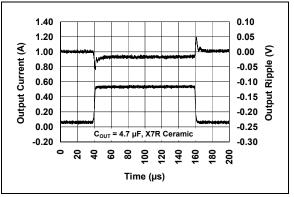


FIGURE 2-16: Load Transient Response.

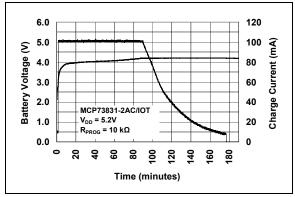


FIGURE 2-17: Complete Charge Cycle (180 mAh Li-Ion Battery).

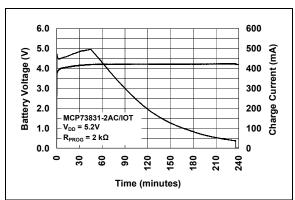


FIGURE 2-18: Complete Charge Cycle (1000 mAh Li-Ion Battery).

NOTES:

3.0 PIN DESCRIPTION

The descriptions of the pins are listed in Table 3-1.

TABLE 3-1: PIN FUNCTION TABLES

Pir	n No.	Cumbal	Function	
DFN	SOT-23-5	Symbol	runction	
1	4	V_{DD}	Battery Management Input Supply	
2	_	V_{DD}	Battery Management Input Supply	
3	3	V_{BAT}	Battery Charge Control Output	
4	_	V_{BAT}	Battery Charge Control Output	
5	1	STAT	Charge Status Output	
6	2	V_{SS}	Battery Management 0V Reference	
7	_	NC	No Connection	
8	5	PROG	Current Regulation Set and Charge Control Enable	
9	_	EP	Exposed Thermal Pad (EP); must be connected to V _{SS} .	

3.1 Battery Management Input Supply (V_{DD})

A supply voltage of [V_{REG} (typical) + 0.3V] to 6V is recommended. Bypass to V_{SS} with a minimum of 4.7 μ F.

3.2 Battery Charge Control Output (V_{RAT})

Connect to positive terminal of battery. Drain terminal of internal P-channel MOSFET pass transistor. Bypass to V_{SS} with a minimum of 4.7 μF to ensure loop stability when the battery is disconnected.

3.3 Charge Status Output (STAT)

STAT is an output for connection to an LED for charge status indication. Alternatively, a pull-up resistor can be applied for interfacing to a host microcontroller.

STAT is a tri-state logic output on the MCP73831 and an open-drain output on the MCP73832.

3.4 Battery Management 0V Reference (V_{SS})

Connect to negative terminal of battery and input supply.

3.5 Current Regulation Set (PROG)

Preconditioning, fast charge and termination currents are scaled by placing a resistor from PROG to V_{SS} .

The charge management controller can be disabled by allowing the PROG input to float.

3.6 Exposed Thermal Pad (EP)

An internal electrical connection exists between the Exposed Thermal Pad (EP) and the V_{SS} pin. They must be connected to the same potential on the Printed Circuit Board (PCB).

For better thermal performance, it is recommended to add vias from the land area of EP to a copper layer on the other side of the PCB.

NOTES:

4.0 DEVICE OVERVIEW

The MCP73831/2 are highly advanced linear charge management controllers. Figure 4-1 depicts the operational flow algorithm from charge initiation to completion and automatic recharge.

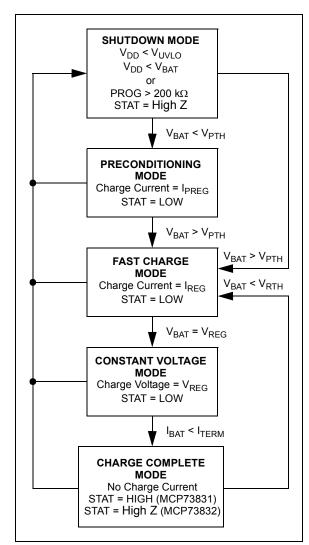


FIGURE 4-1: Flowchart.

4.1 Undervoltage Lockout (UVLO)

An internal UVLO circuit monitors the input voltage and keeps the charger in Shutdown mode until the input supply rises above the UVLO threshold. The UVLO circuitry has a built in hysteresis of 100 mV.

In the event a battery is present when the input power is applied, the input supply must rise to a level 150 mV above the battery voltage before the MCP73831/2 become operational.

The UVLO circuit places the device in Shutdown mode if the input supply falls to within +50 mV of the battery voltage. Again, the input supply must rise to a level 150 mV above the battery voltage before the MCP73831/2 become operational.

The UVLO circuit is always active. Whenever the input supply is below the UVLO threshold or within +50 mV of the voltage at the V_{BAT} pin, the MCP73831/2 are placed in Shutdown mode.

During any UVLO condition, the battery reverse discharge current is less than 2 μA .

4.2 Battery Detection

A 6 μ A (typical) current is sourced by the V_{BAT} pin to determine if a battery is present or not. If the voltage at V_{BAT} rises to V_{REG} + 100 mV (typical), the device assumes that a battery is not present. If the voltage stays below V_{REG} + 100 mV (typical), the device assumes that a battery is detected. In order to correctly detect a battery insertion, the impedance seen by the V_{BAT} pin before the battery is connected must be greater than 2 $M\Omega$.

4.3 Charge Qualification

For a charge cycle to begin, all UVLO conditions must be met and a battery or output load must be present. A charge current programming resistor must be connected from PROG to V_{SS} . If the PROG pin is open or floating, the MCP73831/2 are disabled and the battery reverse discharge current is less than 2 μ A. In this manner, the PROG pin acts as a charge enable and can be used as a manual shutdown.

4.4 Preconditioning

If the voltage at the V_{BAT} pin is less than the preconditioning threshold, the MCP73831/2 enter a preconditioning or Trickle Charge mode. The preconditioning threshold is factory set. Refer to Section 1.0 "Electrical Characteristics" for preconditioning threshold options and the Product Identification System for standard options.

In this mode, the MCP73831/2 supply a percentage of the charge current (established with the value of the resistor connected to the PROG pin) to the battery. The percentage or ratio of the current is factory set. Refer to Section 1.0 "Electrical Characteristics" for preconditioning current options and the Product Identification System for standard options.

When the voltage at the V_{BAT} pin rises above the preconditioning threshold, the MCP73831/2 enter the Constant-Current or Fast Charge mode.

4.5 Fast Charge Constant-Current Mode

During the Constant-Current mode, the programmed charge current is supplied to the battery or load. The charge current is established using a single resistor from PROG to V_{SS} . Constant-Current mode is maintained until the voltage at the V_{BAT} pin reaches the regulation voltage, V_{REG} .

4.6 Constant-Voltage Mode

When the voltage at the V_{BAT} pin reaches the regulation voltage, V_{REG} constant voltage regulation begins. The regulation voltage is factory set to 4.2V, 4.35V, 4.40V or 4.50V with a tolerance of $\pm 0.75\%$.

4.7 Charge Termination

The charge cycle is terminated when, during Constant-Voltage mode, the average charge current diminishes below a percentage of the programmed charge current (established with the value of the resistor connected to the PROG pin). A 1 ms filter time on the termination comparator ensures that transient load conditions do not result in premature charge cycle termination. The percentage or ratio of the current is factory set. Refer to Section 1.0 "Electrical Characteristics" for charge termination current options and the Product Identification System for standard options.

The charge current is latched off and the MCP73831/2 enter a Charge Complete mode.

4.8 Automatic Recharge

The MCP73831/2 continuously monitor the voltage at the V_{BAT} pin in the Charge Complete mode. If the voltage drops below the recharge threshold, another charge cycle begins and current is once again supplied to the battery or load. The recharge threshold is factory set. Refer to Section 1.0 "Electrical Characteristics" for recharge threshold options and the Product Identification System for standard options.

4.9 Thermal Regulation

The MCP73831/2 limit the charge current based on the die temperature. The thermal regulation optimizes the charge cycle time while maintaining device reliability. Figure 4-2 depicts the thermal regulation for the MCP73831/2.

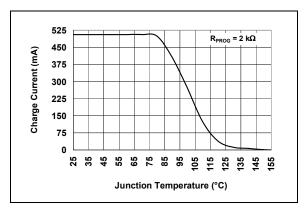


FIGURE 4-2: Thermal Regulation.

4.10 Thermal Shutdown

The MCP73831/2 suspend charge if the die temperature exceeds 150°C. Charging will resume when the die temperature has cooled by approximately 10°C.

5.0 DETAILED DESCRIPTION

5.1 Analog Circuitry

5.1.1 BATTERY MANAGEMENT INPUT SUPPLY (VDD)

The V_{DD} pin is the input supply pin for the MCP73831/2 devices. The MCP73831/2 automatically enter a Power-Down mode if the voltage on the V_{DD} input falls below the UVLO voltage (V_{STOP}). This feature prevents draining the battery pack when the V_{DD} supply is not present.

5.1.2 CURRENT REGULATION SET (PROG)

Fast charge current regulation can be scaled by placing a programming resistor (R_{PROG}) from the PROG input to V_{SS} . The program resistor and the charge current are calculated using the following equation:

$$I_{REG} = \frac{1000V}{R_{PROG}}$$

Where:

 R_{PROG} = kOhms I_{REG} = milliampere

The preconditioning trickle charge current and the charge termination current are ratiometric to the fast charge current based on the selected device options.

5.1.3 BATTERY CHARGE CONTROL OUTPUT (V_{BAT})

The battery charge control output is the drain terminal of an internal P-channel MOSFET. The MCP73831/2 provide constant current and voltage regulation to the battery pack by controlling this MOSFET in the linear region. The battery charge control output should be connected to the positive terminal of the battery pack.

5.2 Digital Circuitry

5.2.1 STATUS INDICATOR (STAT)

The charge status output of the MCP73831 has three different states: High (H), Low (L), and High-Impedance (High Z). The charge status output of the MCP73832 is open-drain. It has two different states: Low (L) and High-Impedance (High Z). The charge status output can be used to illuminate one, two or tri-color LEDs. Optionally, the charge status output can be used as an interface to a host microcontroller.

Table 5-1 summarizes the state of the status output during a charge cycle.

TABLE 5-1: STATUS OUTPUT

Charge Cycle State	STAT1			
Charge Cycle State	MCP73831	MCP73832		
Shutdown	High Z	High Z		
No Battery Present	High Z	High Z		
Preconditioning	L	L		
Constant-Current Fast Charge	L	L		
Constant Voltage	L	L		
Charge Complete – Standby	Н	High Z		

5.2.2 DEVICE DISABLE (PROG)

The current regulation set input pin (PROG) can be used to terminate a charge at any time during the charge cycle, as well as to initiate a charge cycle or initiate a recharge cycle.

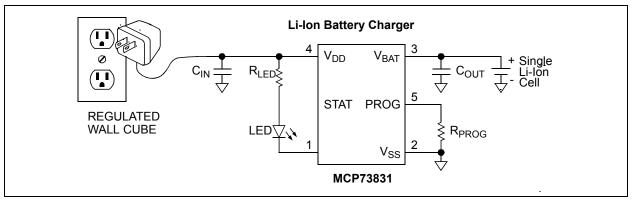
Placing a programming resistor from the PROG input to V_{SS} enables the device. Allowing the PROG input to float or by applying a logic-high input signal, disables the device and terminates a charge cycle. When disabled, the device's supply current is reduced to 25 μ A, typically.

NOTES:

6.0 APPLICATIONS

The MCP73831/2 are designed to operate in conjunction with a host microcontroller or in a standalone application. The MCP73831/2 provide the preferred charge algorithm for Lithium-Ion and Lithium-Polymer cells. The algorithm uses a constant current

followed by a constant voltage charging method. Figure 6-1 depicts a typical stand-alone application circuit, while Figure 6-2 and Figure 6-3 depict the accompanying charge profile.



6.0

FIGURE 6-1: Typical Application Circuit.

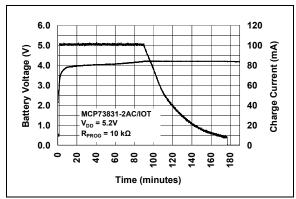


FIGURE 6-2: Typical Charge Profile (180 mAh Battery).

5.0 500 Battery Voltage (V) 4.0 400 3.0 300 2.0 200 MCP73831-2AC/IOT $V_{DD} = 5.2V$ 1.0 100 R_{PROG} = 2 kΩ 0.0 0 30 9 90 20 50 Time (minutes)

600

FIGURE 6-3: Typical Charge Profile in Thermal Regulation (1000 mAh Battery).

6.1 Application Circuit Design

Due to the low efficiency of linear charging, the most important factors are thermal design and cost, which are a direct function of the input voltage, output current and thermal impedance between the battery charger and the ambient cooling air. The worst-case situation is when the device has transitioned from the Preconditioning mode to the Constant-Current mode. In this situation, the battery charger has to dissipate the maximum power. A trade-off must be made between the charge current, cost and thermal requirements of the charger.

6.1.1 COMPONENT SELECTION

Selection of the external components in Figure 6-1 is crucial to the integrity and reliability of the charging system. The following discussion is intended as a guide for the component selection process.

6.1.1.1 Current Programming Resistor (R_{PROG})

The preferred fast charge current for Lithium-Ion cells is at the 1C rate, with an absolute maximum current at the 2C rate. For example, a 500 mAh battery pack has a preferred fast charge current of 500 mA. Charging at this rate provides the shortest charge cycle times without degradation to the battery pack performance or life.

6.1.1.2 Input Overvoltage Protection (IOVP)

Input overvoltage protection must be used when the input power source is hot-pluggable. This includes USB cables and Wall-type power supplies. The cabling of these supplies acts as an inductor. When the supplies are connected/disconnected from the system, large voltage transients are created which may damage the system circuitry. These transients should be snubbed out. A transzorb connected from the V+ input supply connector to the 0V ground reference will snub the transients.

6.1.1.3 Thermal Considerations

The worst-case power dissipation in the battery charger occurs when the input voltage is at the maximum and the device has transitioned from the Preconditioning mode to the Constant-Current mode. In this case, the power dissipation is:

 $PowerDissipation = (V_{DDMAX} - V_{PTHMIN}) \times I_{REGMAX}$

Where:

 V_{DDMAX} = the maximum input voltage

 I_{REGMAX} = the maximum fast charge current

 V_{PTHMIN} = the minimum transition threshold

voltage

Power dissipation with a 5V, ±10% input voltage source is:

 $PowerDissipation = (5.5V - 2.7V) \times 550mA = 1.54W$

This power dissipation with the battery charger in the SOT-23-5 package will cause thermal regulation to be entered as depicted in Figure 6-3. Alternatively, the 2mm x 3mm DFN package could be utilized to reduce charge cycle times.

6.1.1.4 External Capacitors

The MCP73831/2 are stable with or without a battery load. In order to maintain good AC stability in the Constant-Voltage mode, a minimum capacitance of 4.7 μF is recommended to bypass the V_{BAT} pin to V_{SS} . This capacitance provides compensation when there is no battery load. In addition, the battery and interconnections appear inductive at high frequencies. These elements are in the control feedback loop during Constant-Voltage mode. Therefore, the bypass capacitance may be necessary to compensate for the inductive nature of the battery pack.

Virtually any good quality output filter capacitor can be used, independent of the capacitor's minimum Effective Series Resistance (ESR) value. The actual value of the capacitor (and its associated ESR) depends on the output load current. A 4.7 μF ceramic, tantalum or aluminum electrolytic capacitor at the output is usually sufficient to ensure stability for output currents up to a 500 mA.

6.1.1.5 Reverse-Blocking Protection

The MCP73831/2 provide protection from a faulted or shorted input. Without the protection, a faulted or shorted input would discharge the battery pack through the body diode of the internal pass transistor.

6.1.1.6 Charge Inhibit

The current regulation set input pin (PROG) can be used to terminate a charge at any time during the charge cycle, as well as to initiate a charge cycle or initiate a recharge cycle.

Placing a programming resistor from the PROG input to V_{SS} enables the device. Allowing the PROG input to float or by applying a logic-high input signal, disables the device and terminates a charge cycle. When disabled, the device's supply current is reduced to 25 μ A, typically.

6.1.1.7 Charge Status Interface

A status output provides information on the state of charge. The output can be used to illuminate external LEDs or interface to a host microcontroller. Refer to Table 5-1 for a summary of the state of the status output during a charge cycle.

6.2 PCB Layout Issues

For optimum voltage regulation, place the battery pack as close as possible to the device's V_{BAT} and V_{SS} pins. This is recommended to minimize voltage drops along the high current-carrying PCB traces.

If the PCB layout is used as a heat sink, adding many vias in the heat sink pad can help conduct more heat to the PCB backplane, thus reducing the maximum junction temperature. Figure 6-4 and Figure 6-5 depict a typical layout with PCB heatsinking.

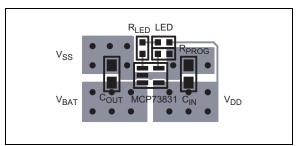


FIGURE 6-4:

Typical Layout (Top).

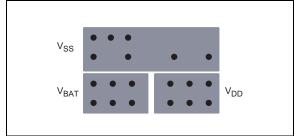


FIGURE 6-5:

Typical Layout (Bottom).

7.0 PACKAGING INFORMATION

7.1 **Package Marking Information**

8-Lead DFN (2x3x0.9 mm)



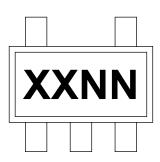
Device	Code			
MCP73831T-2ACI/MC	AAE			
MCP73831T-2ATI/MC	AAF			
MCP73831T-2DCI/MC	AAG			
MCP73831T-3ACI/MC	AAH			
MCP73831T-4ADI/MC	AAJ			
MCP73831T-5ACI/MC	AAK			
MCP73832T-2ACI/MC	AAL			
MCP73832T-2ATI/MC	AAM			
MCP73832T-2DCI/MC	AAP			
MCP73832T-3ACI/MC	AAQ			
MCP73832T-4ADI/MC	AAR			
MCP73832T-5ACI/MC	AAS			
Note: Applies to 8 Load DEN				

Note: Applies to 8-Lead DFN





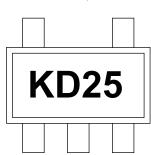
5-Lead SOT-23



Device	Code
MCP73831T-2ACI/OT	KDNN
MCP73831T-2ATI/OT	KENN
MCP73831T-2DCI/OT	KFNN
MCP73831T-3ACI/OT	KGNN
MCP73831T-4ADI/OT	KHNN
MCP73831T-5ACI/OT	KJNN
MCP73832T-2ACI/OT	KKNN
MCP73832T-2ATI/OT	KLNN
MCP73832T-2DCI/OT	KMNN
MCP73832T-3ACI/OT	KPNN
MCP73832T-4ADI/OT	KQNN
MCP73832T-5ACI/OT	KRNN
MCP73832T-2DFI/OT	LUNN

Note: Applies to 5-Lead SOT-23

Example



Legend: XX...X Customer-specific information

Year code (last digit of calendar year) ΥY Year code (last 2 digits of calendar year) WW Week code (week of January 1 is week '01')

NNN Alphanumeric traceability code

e3 Pb-free Compliant JEDEC® designator for Matte Tin (Sn) This package is Pb-free. The Pb-free JEDEC designator (@3)

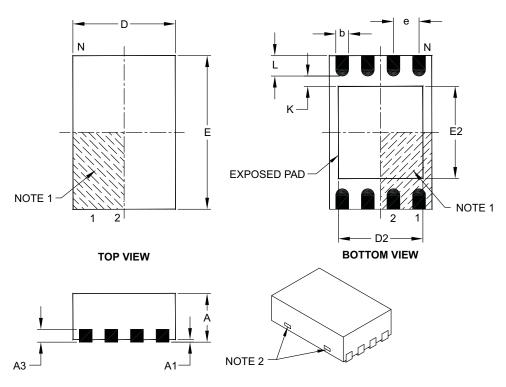
can be found on the outer packaging for this package.

In the event the full Microchip part number cannot be marked on one line, it will be carried over Note: to the next line, thus limiting the number of available characters for customer-specific

information.

8-Lead Plastic Dual Flat, No Lead Package (MC) – 2x3x0.9 mm Body [DFN]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units	MILLIMETERS		
Dimensio	n Limits	MIN	NOM	MAX
Number of Pins	N		8	
Pitch	е		0.50 BSC	
Overall Height	Α	0.80	0.90	1.00
Standoff	A1	0.00	0.02	0.05
Contact Thickness	A3	0.20 REF		
Overall Length	D	2.00 BSC		
Overall Width	Е	3.00 BSC		
Exposed Pad Length	D2	1.30	_	1.55
Exposed Pad Width	E2	1.50	_	1.75
Contact Width	b	0.20	0.25	0.30
Contact Length	L	0.30	0.40	0.50
Contact-to-Exposed Pad	K	0.20	_	_

Notes:

- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. Package may have one or more exposed tie bars at ends.
- 3. Package is saw singulated.
- 4. Dimensioning and tolerancing per ASME Y14.5M.

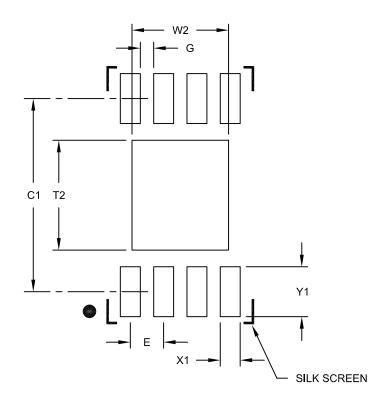
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-123C

8-Lead Plastic Dual Flat, No Lead Package (MC) - 2x3x0.9mm Body [DFN]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

	MILLIMETERS			
Dimension	MIN	NOM	MAX	
Contact Pitch	Е	0.50 BSC		
Optional Center Pad Width	W2			1.45
Optional Center Pad Length	T2	1.7		1.75
Contact Pad Spacing	C1		2.90	
Contact Pad Width (X8)	X1			0.30
Contact Pad Length (X8)	Y1			0.75
Distance Between Pads	G	0.20		

Notes:

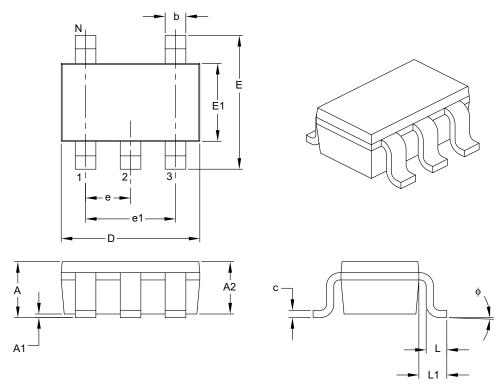
1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2123B

5-Lead Plastic Small Outline Transistor (OT) [SOT-23]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units	MILLIMETERS			
	Dimension Limits	MIN	NOM	MAX	
Number of Pins	N		5	•	
Lead Pitch	е		0.95 BSC		
Outside Lead Pitch	e1		1.90 BSC		
Overall Height	A	0.90	_	1.45	
Molded Package Thickness	A2	0.89	_	1.30	
Standoff	A1	0.00	_	0.15	
Overall Width	E	2.20	_	3.20	
Molded Package Width	E1	1.30	_	1.80	
Overall Length	D	2.70	_	3.10	
Foot Length	L	0.10	_	0.60	
Footprint	L1	0.35	_	0.80	
Foot Angle	ф	0°	_	30°	
Lead Thickness	С	0.08	_	0.26	
Lead Width	b	0.20	_	0.51	

Notes:

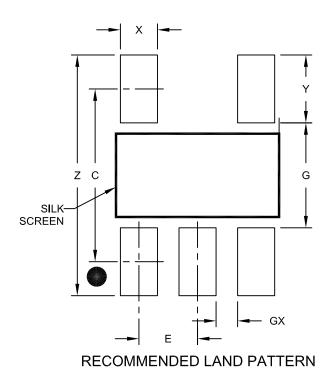
- 1. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.127 mm per side.
- 2. Dimensioning and tolerancing per ASME Y14.5M.

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing C04-091B

5-Lead Plastic Small Outline Transistor (OT) [SOT-23]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Units **MILLIMETERS Dimension Limits** MIN MOM MAX Contact Pitch 0.95 BSC Ε С **Contact Pad Spacing** 2.80 Contact Pad Width (X5) Χ 0.60 Contact Pad Length (X5) Υ 1.10 G 1.70 Distance Between Pads Distance Between Pads GΧ 0.35 Overall Width 3.90 Ζ

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2091A

APPENDIX A: REVISION HISTORY

Revision G (July 2014)

The following is the list of modifications:

- 1. Updated the "DC Characteristics" table.
- Added Section 6.1.1.2 "Input Overvoltage Protection (IOVP)".

Revision F (June 2013)

The following is the list of modifications:

- 3. Updated the Functional Block Diagram.
- Added the Battery Detection parameter and related information in the "DC Characteristics" table.
- Added new section Section 4.2 "Battery Detection".
- 6. Minor grammatical and spelling corrections.

Revision E (September 2008)

The following is the list of modifications:

- 1. Package Types: Changed DFN pinout diagram.
- 2. Section 1.0 "Electrical Characteristics": Changed "Charge Impedance Range from 20 k Ω to 67 k Ω .
- Section 1.0 "Electrical Characteristics": Misc. Formatting changes.
- 4. Section 2.0 "Typical Performance Curves": Updated Figure 2-4.
- Section 3.0 "Pin Description": Added Exposed Pad pin to table and added Section 3.6 "Exposed Thermal Pad (EP)".
- 6. Updated Appendix A: "Revision History"
- 7. Added Land Pattern Package Outline Drawing for 2x3 DFN package.

Revision D (April 2008)

The following is the list of modifications:

1. Changed Charge Termination Current Ratio to 8.5% minimum and 11.5% maximum.

Revision C (October 2007)

The following is the list of modifications:

- 1. Numerous edits throughout document.
- Added note to the Temperature Specifications table.
- Updated Figure 2-4.

Revision B (March 2006)

The following is the list of modifications:

1. Added MCP73832 through document.

Revision A (November 2005)

Original Release of this Document.

PRODUCT IDENTIFICATION SYSTEM

 $\underline{\text{To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.}$

PART NO.	<u>X</u> XX	<u> </u>	/XX		Exa	amples: *
Device		ons Temperatur Range	T	ge	a) b) c)	MCP73831-2ACI/OT: 4.20V V _{REG} , Options AC, 5LD SOT23 Pkg MCP73831T-2ACI/OT: Tape and Reel, 4.20V V _{REG} , Options AC, 5LD SOT23 Pkg MCP73832-2ACI/MC: 4.20V V _{REG} ,
Device:	MCP73831: MCP73831T: MCP73832 MCP73832T:	(Tape and Reel) Single-Cell Charge	Controller Controller		d) a) b)	Options AC, 8LD DFN Package MCP73832T-2ACI/MC: Tape and Reel, 4.20V V _{REG} . Options AC, 8LD DFN Package MCP73831-2ATI/OT: 4.20V V _{REG} . Options AT, 5LD SOT23 Pkg MCP73831T-2ATI/OT: Tape and Reel, 4.20V V _{REG} . Options AT, 5LD SOT23 Pkg
Regulation Voltage:	Code V _{RE} 2 = 4.20 3 = 4.30 4 = 4.40 5 = 4.50	0V 5V 0V			c) d) a) b)	MCP73832-2ATI/MC: 4.20V V _{REG} , Options AT, 8LD DFN Package MCP73832T-2ATI/MC: Tape and Reel, 4.20V V _{REG} , Options AT, 8LD DFN Package MCP73831-2DCI/OT: 4.20V V _{REG} , Options DC, 5LD SOT23 Pkg MCP73831T-2DCI/OT: Tape and Reel,
Options: *	AC AD AT DC	EG/I _{REG} V _{PTH} /V _{REG} 10 66.5 10 66.5 10 71.5 100 x ctory for Alternative De	7.5 7.5 20 7.5	V _{RTH} /V _{REG} 96.5 94 94 96.5	c) d) a)	4.20V V _{REG} . Options DC, 5LD SOT23 Pkg MCP73832-2DCI/MC: 4.20V V _{REG} . Options DC, 8LD DFN Package MCP73832T-2DCI/MC: Tape and Reel, 4.20V V _{REG} . Options DC, 8LD DFN Package MCP73831-3ACI/OT: 4.35V V _{REG} . Options AC, 5LD SOT23 Pkg
Temperature Range:	I = -40	0°C to +85°C (Industria	al)		b) c) d)	MCP73831T-3ACI/OT: Tape and Reel, 4.35V V _{REG} . Options AC, 5LD SOT23 Pkg MCP73832-3ACI/MC: 4.35V V _{REG} . Options AC, 8LD DFN Package MCP73832T-3ACI/MC: Tape and Reel,
Package:		al-Flat, No-Lead (2x3 n aall Outline Transistor (a) b) c) d) a) b) c)	4.35V V _{REG} , Options AC, 8LD DFN Package MCP73831-4ADI/OT: 4.40V V _{REG} , Options AD, 5LD SOT23 Pkg MCP73831T-4ADI/OT: Tape and Reel, 4.40V V _{REG} , Options AD, 5LD SOT23 Pkg MCP73832-4ADI/MC: 4.40V V _{REG} , Options AD, 8LD DFN Package MCP73832T-4ADI/MC: Tape and Reel, 4.40V V _{REG} , Options AD, 8LD DFN Package MCP73831-5ACI/OT: 4.50V V _{REG} , Options AC, 5LD SOT23 Pkg MCP73831T-5ACI/OT: Tape and Reel, 4.50V V _{REG} , Options AC, 5LD SOT23 Pkg MCP73832-5ACI/MC: 4.50V V _{REG} , Options AC, 8LD DFN Package

* Consult Factory for Alternate Device Options

NOTES:

Note the following details of the code protection feature on Microchip devices:

- · Microchip products meet the specification contained in their particular Microchip Data Sheet.
- Microchip believes that its family of products is one of the most secure families of its kind on the market today, when used in the intended manner and under normal conditions.
- There are dishonest and possibly illegal methods used to breach the code protection feature. All of these methods, to our
 knowledge, require using the Microchip products in a manner outside the operating specifications contained in Microchip's Data
 Sheets. Most likely, the person doing so is engaged in theft of intellectual property.
- Microchip is willing to work with the customer who is concerned about the integrity of their code.
- Neither Microchip nor any other semiconductor manufacturer can guarantee the security of their code. Code protection does not mean that we are guaranteeing the product as "unbreakable."

Code protection is constantly evolving. We at Microchip are committed to continuously improving the code protection features of our products. Attempts to break Microchip's code protection feature may be a violation of the Digital Millennium Copyright Act. If such acts allow unauthorized access to your software or other copyrighted work, you may have a right to sue for relief under that Act.

Information contained in this publication regarding device applications and the like is provided only for your convenience and may be superseded by updates. It is your responsibility to ensure that your application meets with your specifications. MICROCHIP MAKES NO REPRESENTATIONS OR WARRANTIES OF ANY KIND WHETHER EXPRESS OR IMPLIED, WRITTEN OR ORAL, STATUTORY OR OTHERWISE, RELATED TO THE INFORMATION, INCLUDING BUT NOT LIMITED TO ITS CONDITION, QUALITY, PERFORMANCE, MERCHANTABILITY OR FITNESS FOR PURPOSE. Microchip disclaims all liability arising from this information and its use. Use of Microchip devices in life support and/or safety applications is entirely at the buyer's risk, and the buyer agrees to defend, indemnify and hold harmless Microchip from any and all damages, claims, suits, or expenses resulting from such use. No licenses are conveyed, implicitly or otherwise, under any Microchip intellectual property rights.

Trademarks

The Microchip name and logo, the Microchip logo, dsPIC, FlashFlex, flexPWR, JukeBlox, KEELoQ, KEELoQ logo, Kleer, LANCheck, MediaLB, MOST, MOST logo, MPLAB, OptoLyzer, PIC, PICSTART, PIC³² logo, RightTouch, SpyNIC, SST, SST Logo, SuperFlash and UNI/O are registered trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

The Embedded Control Solutions Company and mTouch are registered trademarks of Microchip Technology Incorporated in the U.S.A.

Analog-for-the-Digital Age, BodyCom, chipKIT, chipKIT logo, CodeGuard, dsPICDEM, dsPICDEM.net, ECAN, In-Circuit Serial Programming, ICSP, Inter-Chip Connectivity, KleerNet, KleerNet logo, MiWi, MPASM, MPF, MPLAB Certified logo, MPLIB, MPLINK, MultiTRAK, NetDetach, Omniscient Code Generation, PICDEM, PICDEM.net, PICkit, PICtail, RightTouch logo, REAL ICE, SQI, Serial Quad I/O, Total Endurance, TSHARC, USBCheck, VariSense, ViewSpan, WiperLock, Wireless DNA, and ZENA are trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

 $\ensuremath{\mathsf{SQTP}}$ is a service mark of Microchip Technology Incorporated in the U.S.A.

Silicon Storage Technology is a registered trademark of Microchip Technology Inc. in other countries.

GestIC is a registered trademarks of Microchip Technology Germany II GmbH & Co. KG, a subsidiary of Microchip Technology Inc., in other countries.

All other trademarks mentioned herein are property of their respective companies.

© 2005-2014, Microchip Technology Incorporated, Printed in the U.S.A., All Rights Reserved.

ISBN: 978-1-63276-375-4

QUALITY MANAGEMENT SYSTEM CERTIFIED BY DNV = ISO/TS 16949=

Microchip received ISO/TS-16949:2009 certification for its worldwide headquarters, design and wafer fabrication facilities in Chandler and Tempe, Arizona; Gresham, Oregon and design centers in California and India. The Company's quality system processes and procedures are for its PIC® MCUs and dsPIC® DSCs, KEELOQ® code hopping devices, Serial EEPROMs, microperipherals, nonvolatile memory and analog products. In addition, Microchip's quality system for the design and manufacture of development systems is ISO 9001:2000 certified.



Worldwide Sales and Service

AMERICAS

Corporate Office 2355 West Chandler Blvd. Chandler, AZ 85224-6199

Tel: 480-792-7200 Fax: 480-792-7277 Technical Support:

http://www.microchip.com/

support
Web Address:

www.microchip.com

Atlanta Duluth, GA

Tel: 678-957-9614 Fax: 678-957-1455

Austin, TX Tel: 512-257-3370

Boston

Westborough, MA Tel: 774-760-0087 Fax: 774-760-0088

Chicago Itasca, IL

Tel: 630-285-0071 Fax: 630-285-0075

Cleveland

Independence, OH Tel: 216-447-0464 Fax: 216-447-0643

Dallas

Addison, TX Tel: 972-818-7423 Fax: 972-818-2924

Detroit Novi, MI

Tel: 248-848-4000

Houston, TX Tel: 281-894-5983

Indianapolis Noblesville, IN

Tel: 317-773-8323 Fax: 317-773-5453

Los Angeles

Mission Viejo, CA Tel: 949-462-9523 Fax: 949-462-9608

New York, NY Tel: 631-435-6000

San Jose, CA Tel: 408-735-9110

Canada - Toronto Tel: 905-673-0699 Fax: 905-673-6509

ASIA/PACIFIC

Asia Pacific Office

Suites 3707-14, 37th Floor Tower 6, The Gateway Harbour City, Kowloon Hong Kong

Tel: 852-2943-5100 Fax: 852-2401-3431

Australia - Sydney

Tel: 61-2-9868-6733 Fax: 61-2-9868-6755

China - Beijing

Tel: 86-10-8569-7000 Fax: 86-10-8528-2104

China - Chengdu Tel: 86-28-8665-5511

Fax: 86-28-8665-7889 China - Chongqing

Tel: 86-23-8980-9588 Fax: 86-23-8980-9500

China - Hangzhou Tel: 86-571-8792-8115

Fax: 86-571-8792-8116

China - Hong Kong SAR

Tel: 852-2943-5100 Fax: 852-2401-3431

China - Nanjing Tel: 86-25-8473-2460 Fax: 86-25-8473-2470

China - Qingdao Tel: 86-532-8502-7355

Fax: 86-532-8502-7205 China - Shanghai

Tel: 86-21-5407-5533 Fax: 86-21-5407-5066

China - Shenyang Tel: 86-24-2334-2829 Fax: 86-24-2334-2393

China - Shenzhen Tel: 86-755-8864-2200 Fax: 86-755-8203-1760

China - Wuhan Tel: 86-27-5980-5300

Tel: 86-27-5980-5300 Fax: 86-27-5980-5118

China - Xian

Tel: 86-29-8833-7252 Fax: 86-29-8833-7256

China - Xiamen Tel: 86-592-2388138 Fax: 86-592-2388130

China - Zhuhai Tel: 86-756-3210040 Fax: 86-756-3210049

ASIA/PACIFIC

India - Bangalore

Tel: 91-80-3090-4444 Fax: 91-80-3090-4123

India - New Delhi

Tel: 91-11-4160-8631 Fax: 91-11-4160-8632

India - Pune

Tel: 91-20-3019-1500

Japan - Osaka Tel: 81-6-6152-7160

Fax: 81-6-6152-9310

Japan - Tokyo

Tel: 81-3-6880- 3770 Fax: 81-3-6880-3771

Korea - Daegu Tel: 82-53-744-4301

Fax: 82-53-744-4301

Korea - Seoul Tel: 82-2-554-7200 Fax: 82-2-558-5932 or

82-2-558-5934

Malaysia - Kuala Lumpur

Tel: 60-3-6201-9857 Fax: 60-3-6201-9859

Malaysia - Penang

Tel: 60-4-227-8870 Fax: 60-4-227-4068

Philippines - Manila

Tel: 63-2-634-9065 Fax: 63-2-634-9069

Singapore

Tel: 65-6334-8870 Fax: 65-6334-8850

Taiwan - Hsin Chu

Tel: 886-3-5778-366 Fax: 886-3-5770-955

Taiwan - Kaohsiung Tel: 886-7-213-7830

Taiwan - Taipei

Tel: 886-2-2508-8600 Fax: 886-2-2508-0102

Thailand - Bangkok

Tel: 66-2-694-1351 Fax: 66-2-694-1350

EUROPE

Austria - Wels

Tel: 43-7242-2244-39 Fax: 43-7242-2244-393

Denmark - Copenhagen

Tel: 45-4450-2828 Fax: 45-4485-2829

France - Paris

Tel: 33-1-69-53-63-20 Fax: 33-1-69-30-90-79

Germany - Dusseldorf Tel: 49-2129-3766400

Germany - Munich Tel: 49-89-627-144-0

Fax: 49-89-627-144-44 **Germany - Pforzheim**

Tel: 49-7231-424750

Italy - Milan

Tel: 39-0331-742611 Fax: 39-0331-466781

Italy - Venice

Tel: 39-049-7625286

Netherlands - Drunen Tel: 31-416-690399

Fax: 31-416-690340 Poland - Warsaw

Tel: 48-22-3325737

Spain - Madrid

Tel: 34-91-708-08-90 Fax: 34-91-708-08-91

Sweden - Stockholm Tel: 46-8-5090-4654

UK - Wokingham

Tel: 44-118-921-5800 Fax: 44-118-921-5820

03/25/14

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Battery Management category:

Click to view products by Microchip manufacturer:

Other Similar products are found below:

MP26121DQ-LF-P NCP1855FCCT1G FAN54063UCX LC05132C01NMTTTG SN2040DSQR ME4075AM5G AP5054HTCER XPD977B

XPD977B18 4056H DW01 DW06 CM1002-UD CM1002-W CM1002-X CM1002-Y CM1006-B CM1006-Q CM1006-WB CM1006-LCD

CM1006-LBD CM1006-WF CM1006-LF CM1006-WG CM1006-WH CM1006-LG CM1003-S02BD CM1003-S09EA CM1003-S10ED

CM1003-S11ED CM1003-S12BC CM1003-S13CC CM1003-S24BC CM1003-S26BC CM1003-WAD CM1003-BBD CM1003-BFD

CM1003-BND CM1003-BLD CM1003-DAD CM1003-BMD CM1003-BPD CM1003-BKD CM1003-BAE CM1003-BHE CM1102B-FF

CM1102B-FD CM1102B-GD CM1112-DAE CM1112-DBE